

INF5490 RF MEMS

LN01: Introduction. MEMS in RF

Spring 2011, Oddvar Søråsen
Department of informatics, UoO

Today's lecture

- Background for the course INF5490/9490
- Course plan spring 2011
- Introduction
 - MEMS in general
 - RF systems
 - MEMS in RF systems

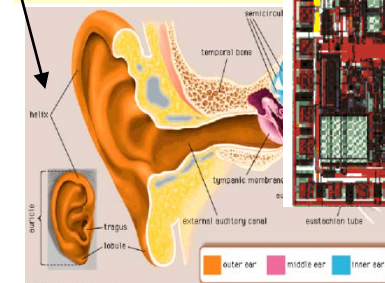
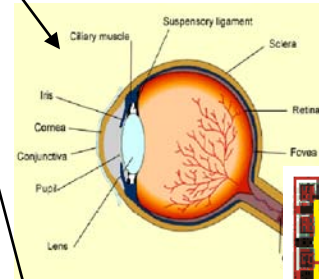
INF5490 RF MEMS

- **MEMS** (Micro Electro **Mechanical** Systems)
 - A relatively new research activity in the NANO group
 - NANO competence: Design of micro/nano- electronic systems: modeling, analysis and implementation of analog and digital VLSI circuits and systems
- Activity inspired by:
 - **National focus** on micro- and nano-technology
 - The Research Council of Norway
 - **MiNaLab** (Micro Nano Technology-lab), next-door
 - SINTEF lab
 - UiO lab

Why MEMS in the Nano-group?

- New possibilities to implement **integrated, miniaturized systems**
 - Electronic systems integrating MEMS give a new **degree of freedom** for designers
 - **A.** May integrate micro **mechanical** components in the systems: add: **"eyes, ears, hands"**
 - **B.** MEMS – components need **interfacing** electronics!

MEMS



Electronics

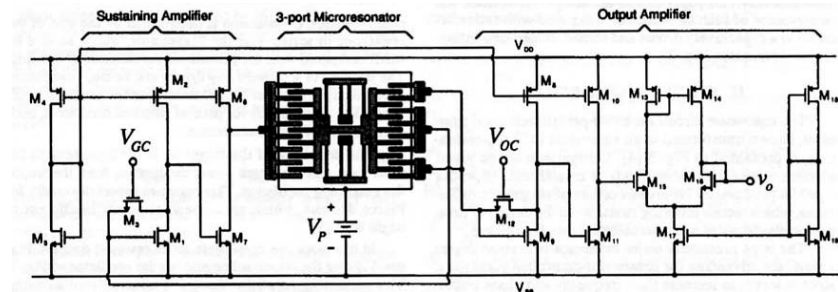
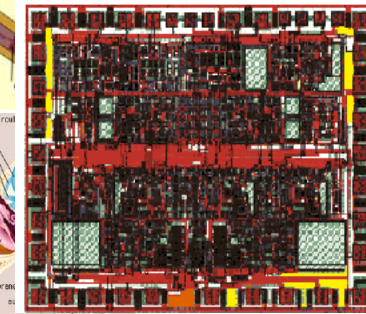
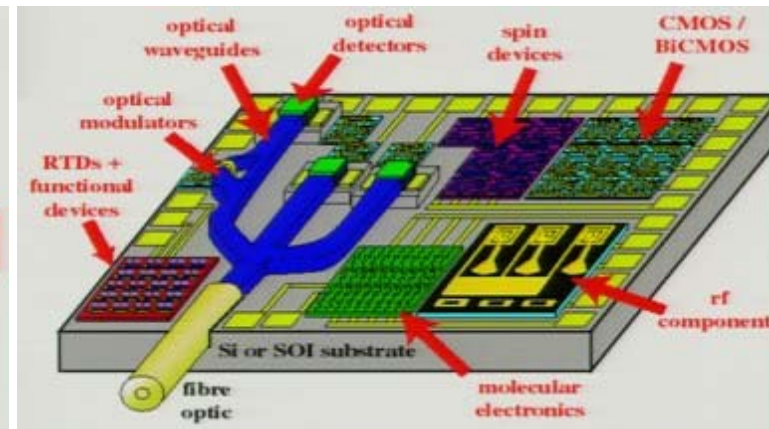
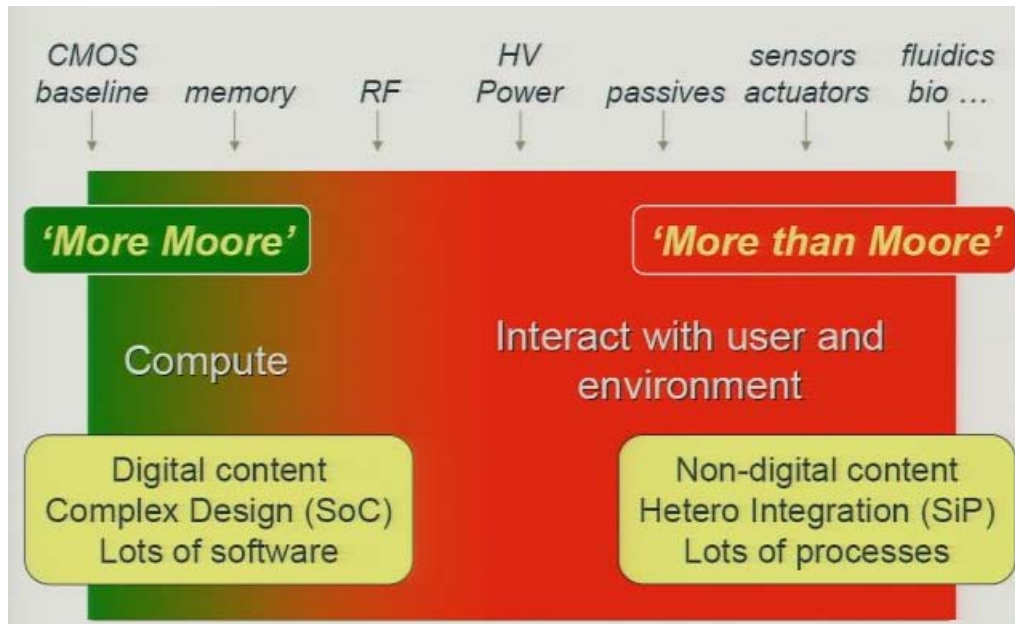
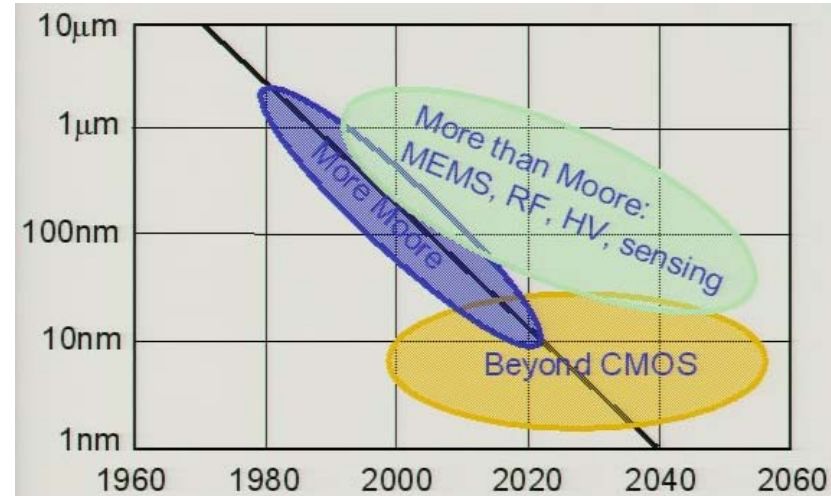


Fig. 4: Circuit schematic for the microresonator oscillator.

Interfacing to the "real world"

- Enhancing "More Moore" by "non-classical" electronic components
- Achieve "Ambient Intelligence" by "More than Moore"



Technology trends

Driven by Moore's Law

1970

1



Computational Infrastructure

- Stationary/backend
- Wired
- High end computing

1980

10



Mobile access devices

- Human interaction
- Portable
- Mostly wireless
- Battery

1980

2000

>100



Sensory swarm

- Miniature
- Wireless
- Autonomous/self-contained
- Controlling and sensing natural processes

2010

Beyond Moore

Personal competence

Background

- Physics
- → modeling and design of VLSI (ASIC)
- → system design
- → computer architecture/multiprocessors

- → **RF MEMS, CMOS-MEMS cointegration**

- Sabbatical at SINTEF MiNaLab 03/04

- Supervising students i relevant fields (Master, Ph.D.)

- Research activities

Input

- Seminars
 - RF MEMS-seminar by A.M. Ionescu, EPFL, at KTH H04
 - Arr: FSRM, Swiss Foundation for Research in Microtechnology
 - RF MEMS tutorial: G.M. Rebeiz, UCSD, in Tønsberg H05
 - Arr: IMAPS Nordic Conference
 - Workshop on MEMS, IMEC, Leuven, H07
 - Arr: Europractice/STIMESI
 - Course on Cofabrication of MEMS and CMOS, IMEC, Leuven, H08
 - Tutorials and conference: Eurosensors XXIII, Lausanne, H09

- Visiting UC Berkeley and Carnegie Mellon University, H06
 - C.T.-C. Nguyen, G.K. Fedder ++

- Literature studies

- Using the simulation package CoventorWare

Selecting a focus → RF MEMS

- MEMS is a broad field of research
 - A focus is needed
 - → RF MEMS
 - → Cofabrication of MEMS and CMOS
- ***”RF MEMS refers to the design and fabrication of dedicated MEMS for RF (integrated) circuits”***
 - 1a) Components **operate** micromechanical **and/or**
 - 1b) Components **fabricated** using micromachining
 - 2) Components are used in **RF systems**

Course topic: RF MEMS

- Observe: **2 disciplines** involved: **RF** and **MEMS**
- **RF** – "Radio frequency"
 - High frequencies: MHz, GHz
 - Used in wireless transmission
 - Many characteristic, special properties related to **high frequency designs**
 - Course, Fall (Tor Fjeldly), **recommended!**
 - **INF5480 RF-circuits, theory and design**
 - Central/ "needed" RF topics for INF5490/9490 are covered in this course

Why RF MEMS in the NANO group?

- Challenging, promising and exciting field!
- Close connection to the basic NANO competence in circuit technology
- The course fits well into the NANO Master/PhD education
- Actual theme
 - Increasing interest internationally for using MEMS in RF systems
- Growing commercial attention
- Basis for establishing new enterprises
- Large market: **wireless communication**
 - Tele communication, mobile business
 - **Wireless Sensor Networks (WSNs)**
 - Distributed intelligence (observation, actuation)
 - Environmental surveillance, – sensor nodes
 - Ambient Intelligence: - units everywhere!
 - Patient surveillance, - medical implants
 - "Internet of things"

International activity

- RF MEMS is in focus on leading international **conferences**
 - ISSCC, IEDM (Int. Electron Devices Meeting), Eurosensors
 - MEMS-conferences and journals
 - See NANO web-page!
- ***Europractice*** and ***CMP*** offer MPW (Multi Project Wafer)
- Increased industry attention and support of RF MEMS
 - Great potential
 - Miniaturization, increased performance, volume production
 - **BUT MEMS in general is not yet a big hit!**
 - **A few successes: airbag sensor, video projector**

MEMS in RF-systems

- RF MEMS development started in the 90s
 - 1990: the first MEMS microwave **switch** better than GaAs (Hughes Res Lab)
 - 1995: RF MEMS switches from Rockwell Science & TI
 - From 1998: some **universities** do research in RF MEMS
 - Univ of Michigan, Univ of Calif Berkeley, Northeastern Univ, MIT, Columbia Univ, CMU (Carnegie Mellon), etc.
 - Some relevant **companies**:
 - Analog Devices, Motorola, Samsung, ST Microelectronics
 - **Research institutes**
 - Sandia, Fraunhofer, IMEC, LETI, SINTEF

RF MEMS: where should I look for?

Top authors, books and web pages

RF MEMS

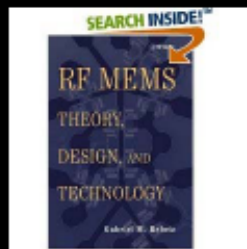
- Clark Nguyen

<http://www.eecs.berkeley.edu/~ctnguyen/>

RF MEMS

- Gabriel Rebeitz

RF MEMS: Theory, Design, and Technology, Wiley, 2003.



NEMS

- Michael Roukes

<http://nano.caltech.edu/>

Adrian M. Ionescu



Nanoscale Systems:

Fundamental & Device Nano-Physics, Bio/Medical Applications, Very-Large-Scale Integration

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We are working to explore new physics at the nanoscale, and to apply this knowledge to realizing advanced tools for the biomedical and life sciences. Our group's efforts span from very systematic nanodevice engineering for practical applications, to biological investigations enabled by novel devices, to quantum measurements with nanosystems at ultralow temperatures.

Our efforts are part of the [Kavli Nanoscience Institute](#) (KNI) at Caltech. Through generous support from both the Gordon and Betty Moore Foundation and the Kavli Foundation, the Caltech "nanoscience community" has been able to assemble state-of-the-art nanofabrication facilities that now enable our work; these facilities include capabilities for 150mm wafer-scale patterning of complex nanodevices with dimensions down to the tens nanometer regime.

Today's lecture

- Background for course INF5490
- Course plan spring 2011
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 - MEMS in general
 - RF-systems
 - MEMS in RF-systems

Information about course INF5490

- Course homepage:
 - <http://www.uio.no/studier/emner/matnat/ifi/INF5490/v11/>
 - Messages posted there! **CHECK regularly!**
- Weekly **lectures**: Oddvar Søråsen, Jan Erik Ramstad
 - Thursday 10:15 – 12 in Pascal 2452
 - Detailed lectureplan on web
 - Lecture notes will be posted on web before lecture (pdf)
- Language: English (if requested by someone from audience)

Group assignments

- **Class assignments:** Srinivasa Reddy Kuppi Reddi
 - "Felles gruppe" – consult web for weekly plan!
 - Tuesday 14:15 – 16 in Pascal 2452
 - First time 25/1
 - Present plan and topics for "obliger"
 - Present supporting literature
 - Work through week assignments
 - Posted a week before
 - Practical aspects
 - Questions, discussion

Obliger

- **2 “obliger”** have to be done
 - Must hand in 2 reports at specified dates (see web)
 - **General guidelines available on web!**
 - **Approval** required for taking the exam!
 - Each group consists of 2 students that collaborate
- Topics: micromechanical resonators and filters
 - Simulations using **CoventorWare**
 - 3-dim modeling, FEM-analysis (Finite-Element-Method)
 - High-level modeling, ARCHITECT

CoventorWare: features

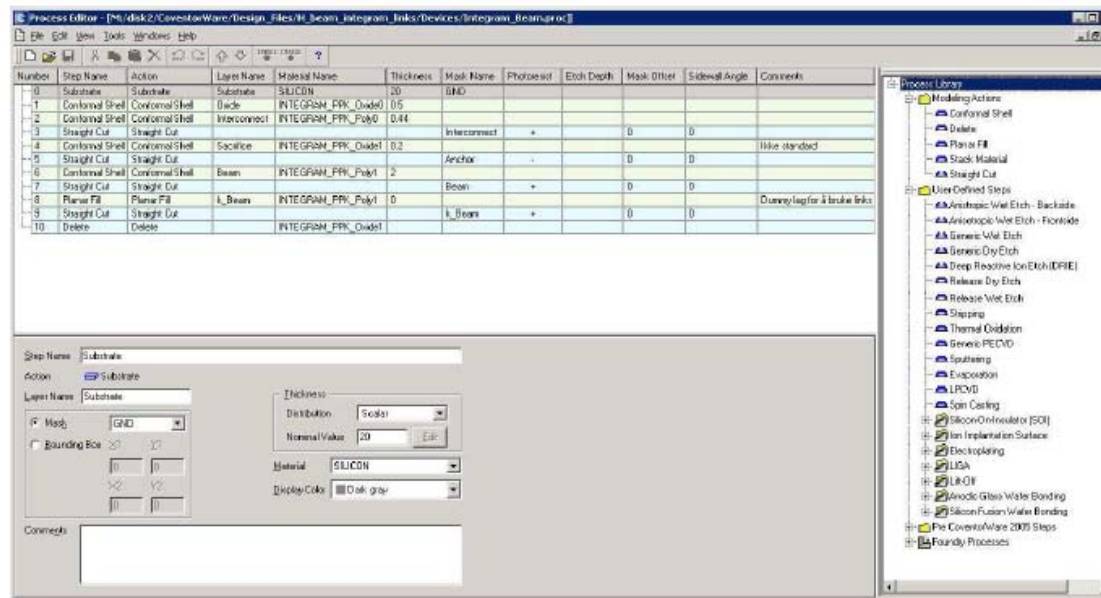
- “State-of-the-art” tool for FEM analysis
 - ”Finite-Element-Method”
- **“Bottom-up” prosedyre:**
 - 1) Build a 3D -model
 - Multiple layers: structural and sacrificial layers
 - Etching pattern, remove sacrificial layer
 - 2) Meshing
 - Tetrahedral, “Manhattan bricks”
 - 3) Solvers
 - Electrical/ mechanical/ coupled
 - Iterate!

COVENTOR

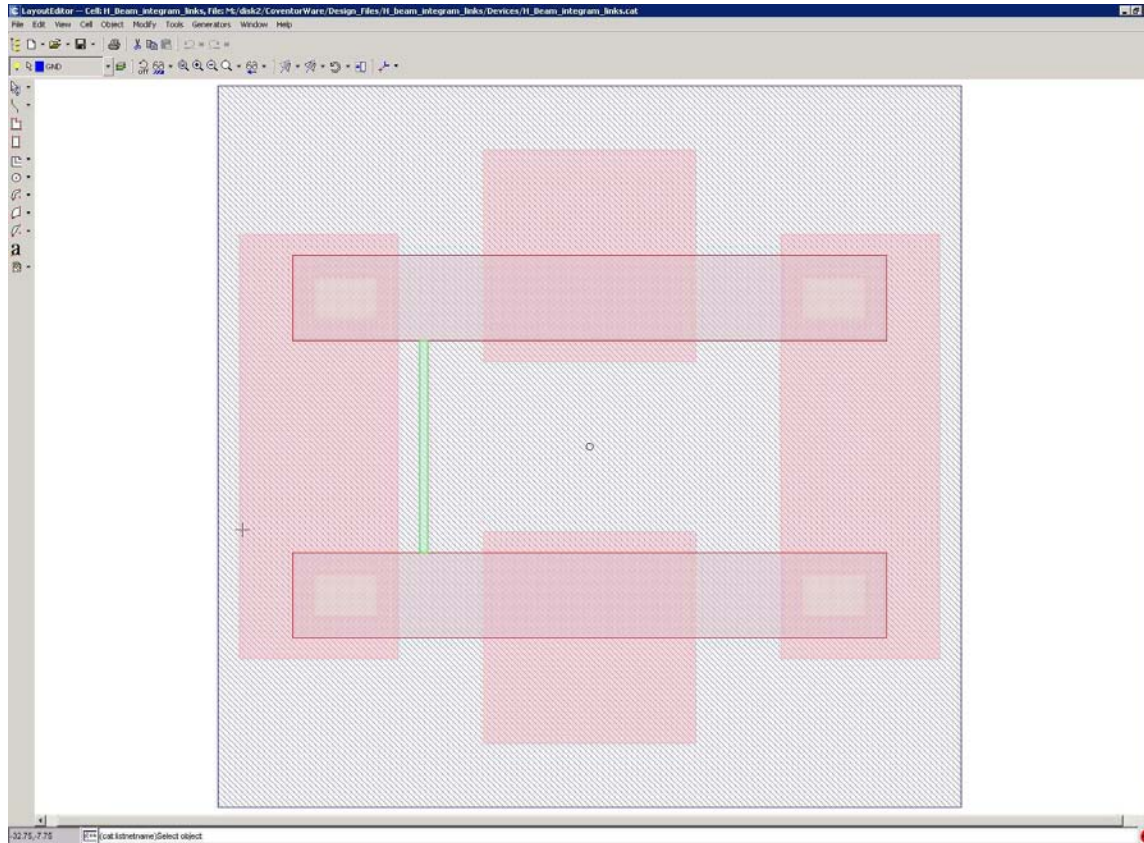
ACCELERATING
MEMS Innovations™

Process-description

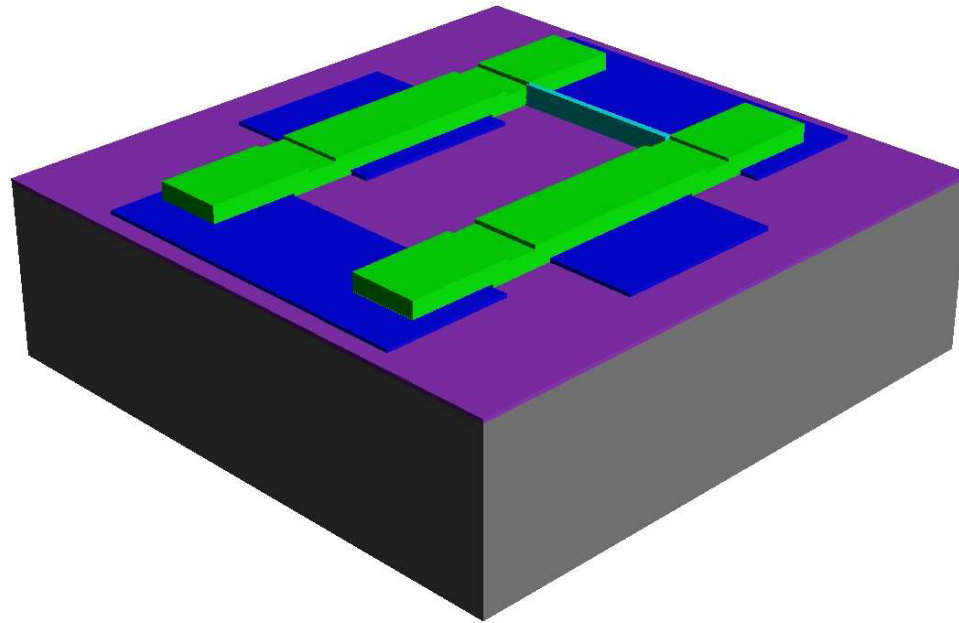
- Specify a **process file** compatible with the relevant “foundry” -process
 - Reduce complexity, idealization
 - Realistic: characteristic process features should be kept



Layout

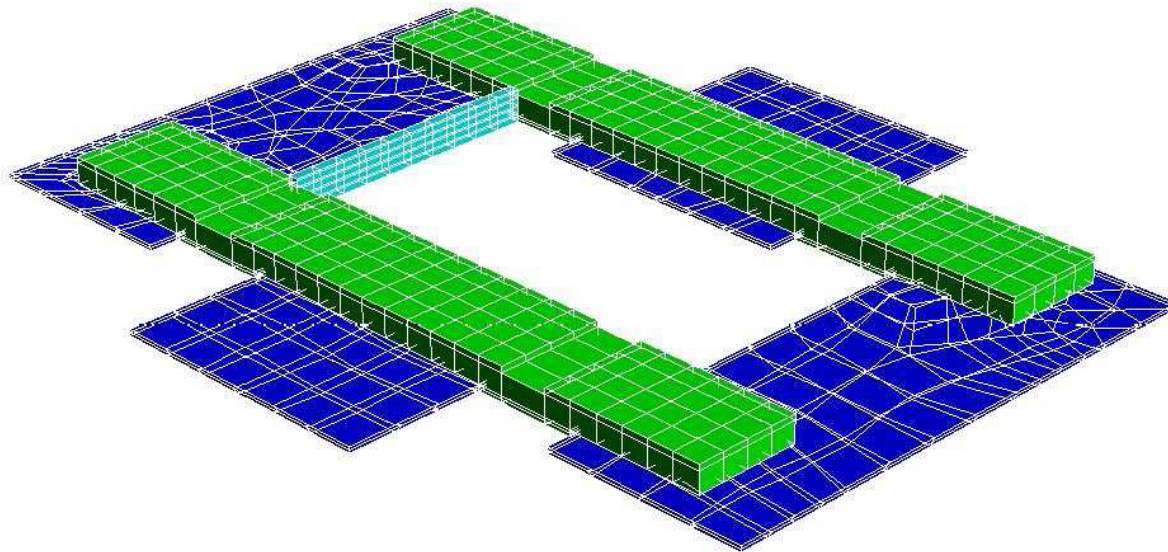


Building a 3-D model

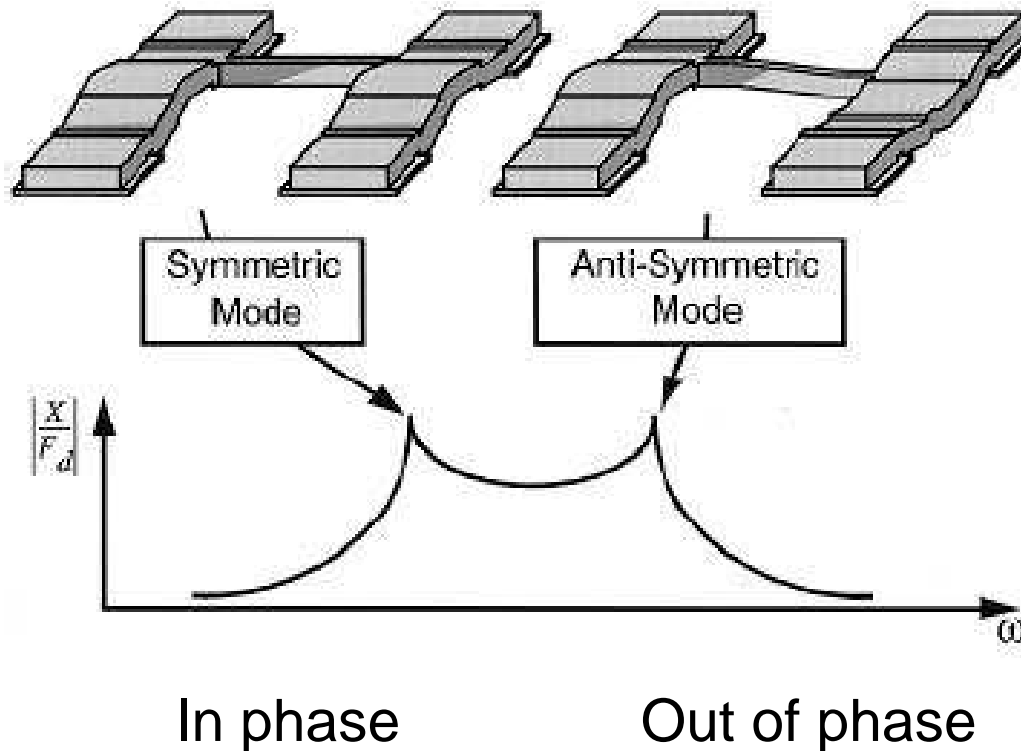


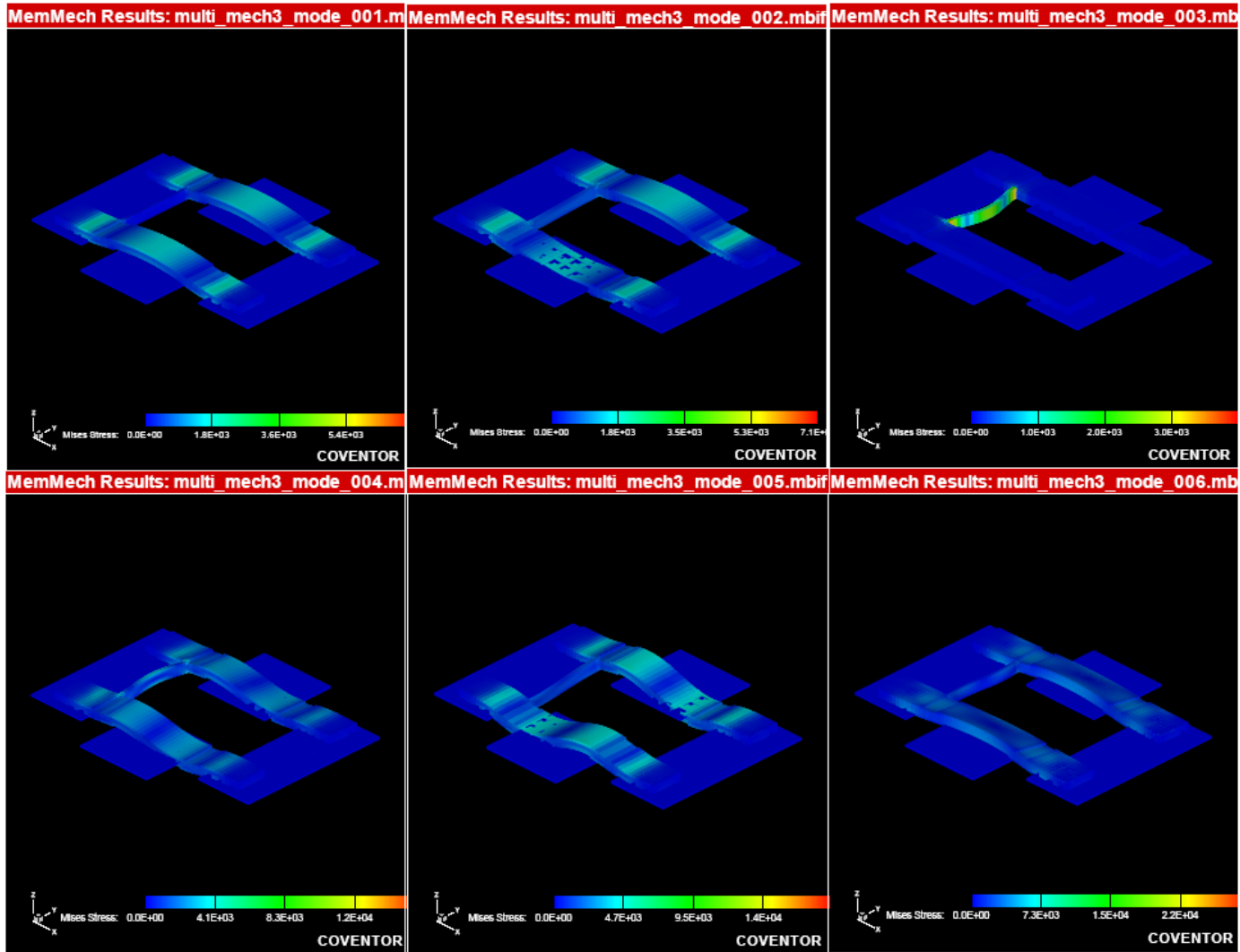
O-P Arhaug

Meshed 3D -model for FEM analysis



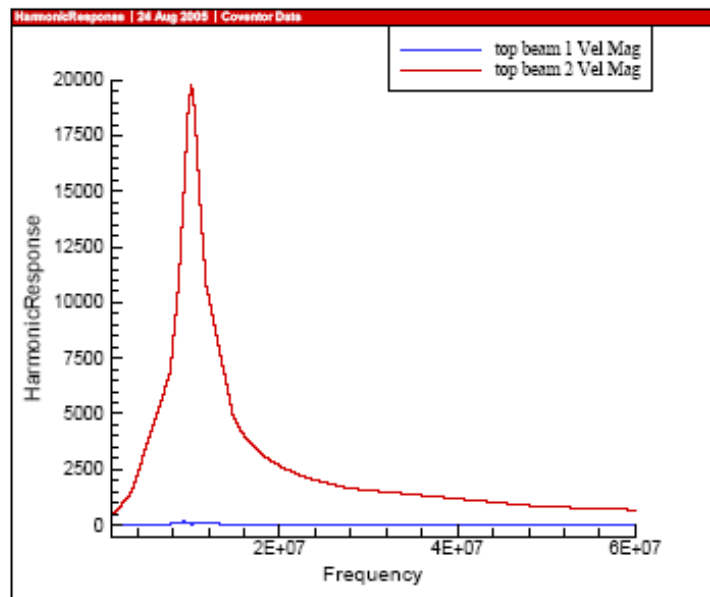
Filter-function: 2 identical resonators



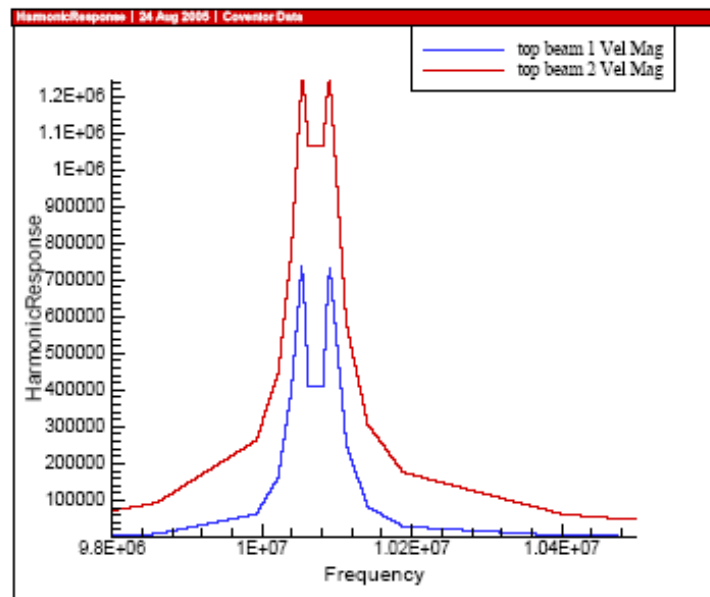


CoventorWare simulations for 6 resonating modes (O-P Arhaug)

Harmonic response for specific dampings



(a) 0,1



(b) 0,001

Exam

- Oral **exam** (45 min)
 - Option II: 3 hours written exam
 - Depending on the number of students
- Relevant exam questions will be posted on web later on
 - Lists for 2009/2010 questions are available now!

Themes covered in the course

- RF MEMS is a **multi disciplinary** field
- **Main topics:**
 - *Introduction* (1 week)
 - *Micromachining* (1 week)
 - *Modeling* (1 week)
 - *RF circuit design* (1 week)
 - ***Typical RF MEMS circuit elements*** (8 weeks)
 - *Operation principles, models/analysis and examples*
 - *Switches, phase shifters, resonators, filters, capacitors and inductors*
 - *Packaging* (1 week)
 - *RF system design* (1 week)
 - *Repetition* (1 week)

Literature

- Text book
 - Vijay K. Varadan, K.J. Vinoy, K.A. Jose, "*RF MEMS and their applications*". John Wiley, 2003. ISBN 0-470-84308-X
 - Supplementary: Ville Kaajakari: "*Practical MEMS*", Small Gear Publishing, 2009. ISBN: 978-0-9822991-0-4
 - No single book does cover the course completely
- Lecture notes: **IMPORTANT!**
 - → Most of the syllabus is covered as lecture notes (ca. 1000)
 - Posted on web before lecture
- INF9490 version: Additional curriculum (updates to be specified)!
- Supporting literature?
 - Overview of literature given on the web course page, e.g.:
 - Gabriel M. Rebeiz, "*RF MEMS, Theory, Design, and Technology*". John Wiley, 2003. ISBN 0-471-20169-3
 - Stephen D. Senturia, "*Microsystem Design*", Kluwer Academic Publishers, 2001. ISBN 0-7923-7246-8

Contact information

- Responsible lecturer
 - Oddvar Søråsen, room 5412, phone: 22 85 24 56
 - oddvar@ifi.uio.no
- Additional lecturer
 - Jan Erik Ramstad, room 5401, phone 22 85 29 28
 - janera@ifi.uio.no
- Responsible for groups/obliger/CoventorWare:
 - Srinivasa Reddy Kuppi Reddi, room 5401, phone 22 84 01 36
 - srinivar@ifi.uio.no
- Contact person CoventorWare: support
 - Yngve Hafting, room 4406, phone: 22 85 16 91
 - yngveha@ifi.uio.no
- web pages
 - <http://www.uio.no/studier/emner/matnat/ifi/INF5490/v11/>

Quality assurance

- Course assessor
 - Chief Scientist Geir Uri Jensen, SINTEF ICT, MiNaLab
- Quality assessment
 - The course coordinator is required to engage students in continuous **evaluation of the course**, offering the students an opportunity to provide continuous **feedback** on the quality of the course. Thus, the course coordinator can make **improvements** based on this feedback

“Institutt for informatikk ønsker en kontinuerlig evaluering av både form og innhold i undervisningen.

Evalueringen skal gi studentene ved et emne mulighet til å komme med tilbakemeldinger underveis, slik at eventuelle forbedringer kan gjøres umiddelbart.

I tillegg skal underveisevalueringen hjelpe faglærer og instituttet til å fange opp god og mindre god undervisningspraksis og heve kvaliteten på emnet/undervisningen.

Emneansvarlig lærer utformer evalueringsopplegget i samråd med studentene som følger emnet og er ansvarlig for kunngjøring av tidspunkt og gjennomføring. Omfang og evalueringsmetode tilpasses hvert enkelt emne og avgjøres av faglærer.

Faglærer utfører eventuelle forbedringer og kommuniserer resultatet til studentene.”

Today's lecture

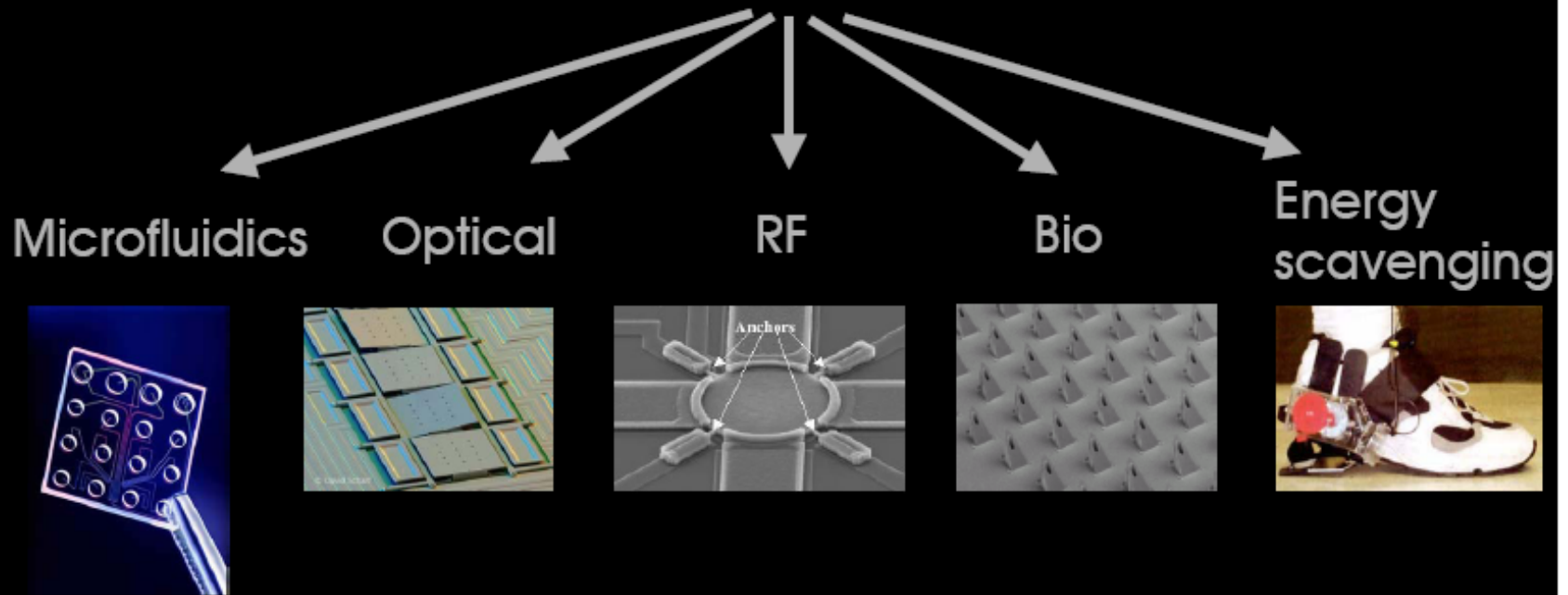
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 - MEMS in general: “- a flavour –”
 - RF-systems
 - MEMS in RF-systems

The Technology is MEMS

- MEMS – Micro Electro Mechanical Systems
 - “Microsystems”
 - “MST, Micro System Technology”
 - → “NEMS” (“nano”...), “MEM/NEM”
- **“Micromachining” is basic!**
 - Further developments of IC fabrication (Silicon)
 - Various MEMS processes available today
 - Often proprietary, specialized for a product
 - Restricted possibilities for “second sourcing” (different from CMOS)
 - Other materials can be involved: plastic and organic materials (polymeres)
- General course on MEMS given by Liv Furuberg, SINTEF, in the fall semester, **recommended!**
 - [FYS4230 Micro- and nanosystem modeling and design](#)
 - Some central topics are recapitulated in INF5490
- **MEMS is a promising technology for RF applications**

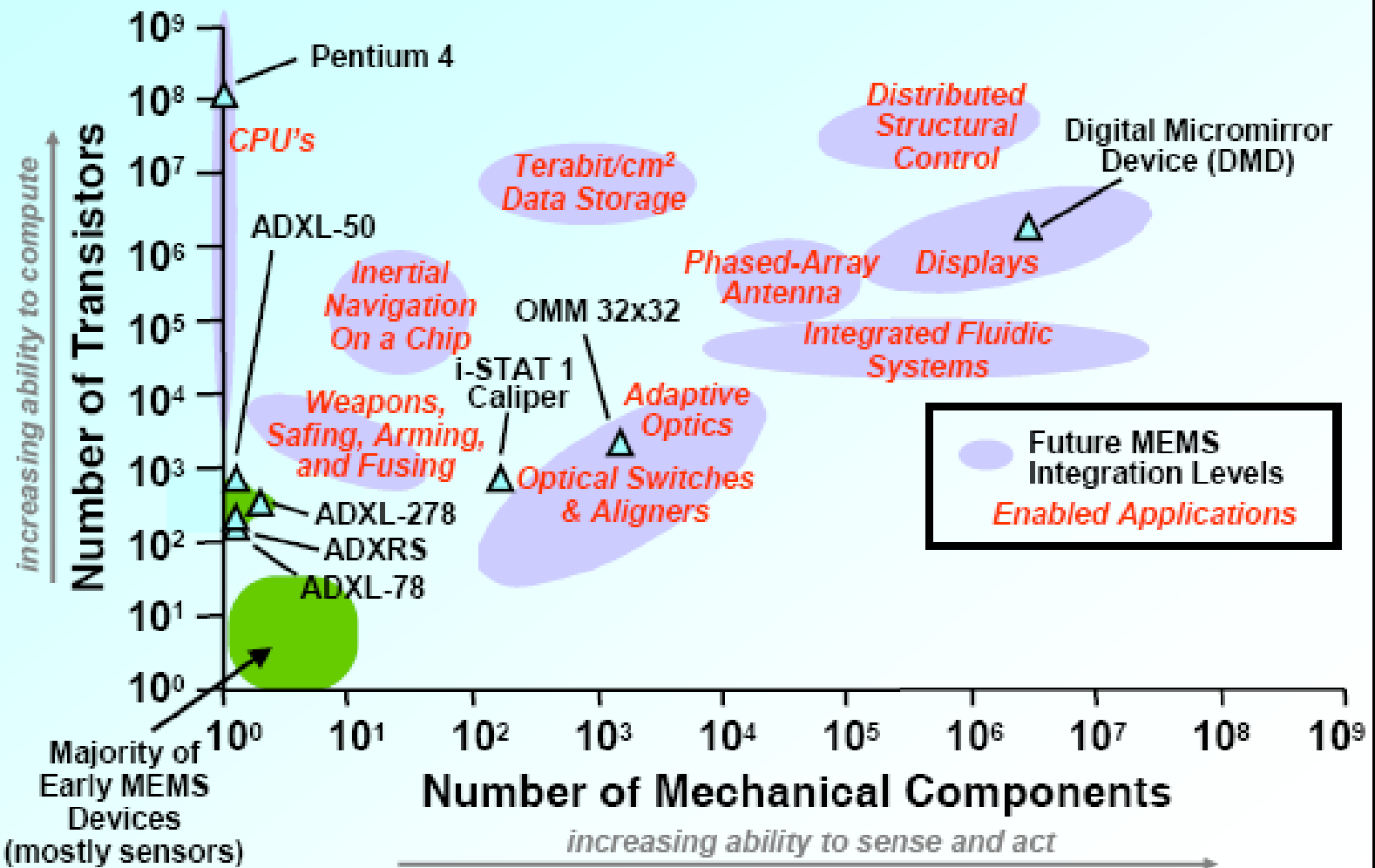
MEMS as enabling technology

MEMS = Micro-Electro-Mechanical Systems

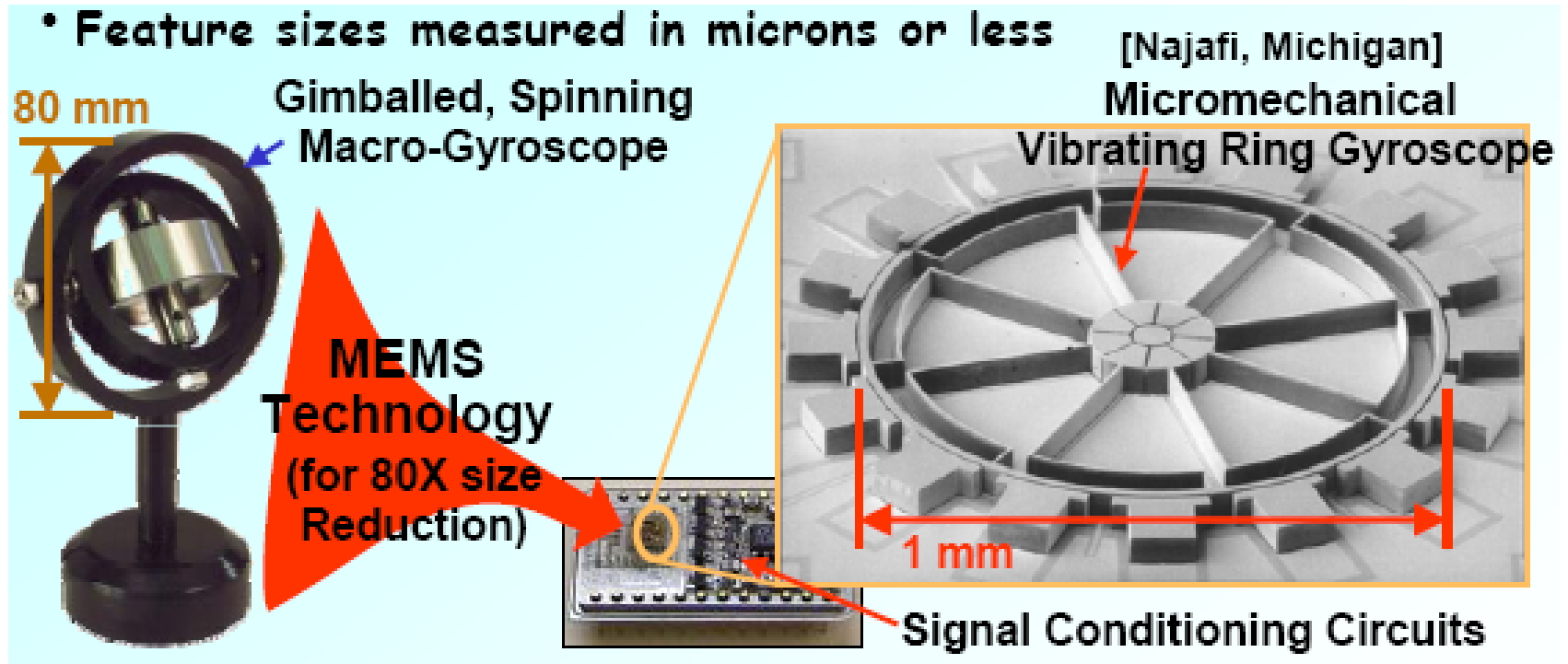


Functionalities you cannot perform with pure electronic functions

Technology Trend and Roadmap for MEMS



"Scaling" is fundamental



[C. Nguyen]

MEMS in general

- 2 types of units: sensors and actuators
 - **Sensor:** (input)
 - "Feels"/ are influenced by environment
 - Movement is transformed to electrical signals
 - Many examples (pressure, acceleration)
 - The earliest applications (1980s)
 - **Actuator:** (output)
 - Movable structure controlled by electric circuit
 - Ex. Micro motor
 - Ex. Capacitor with movable plates

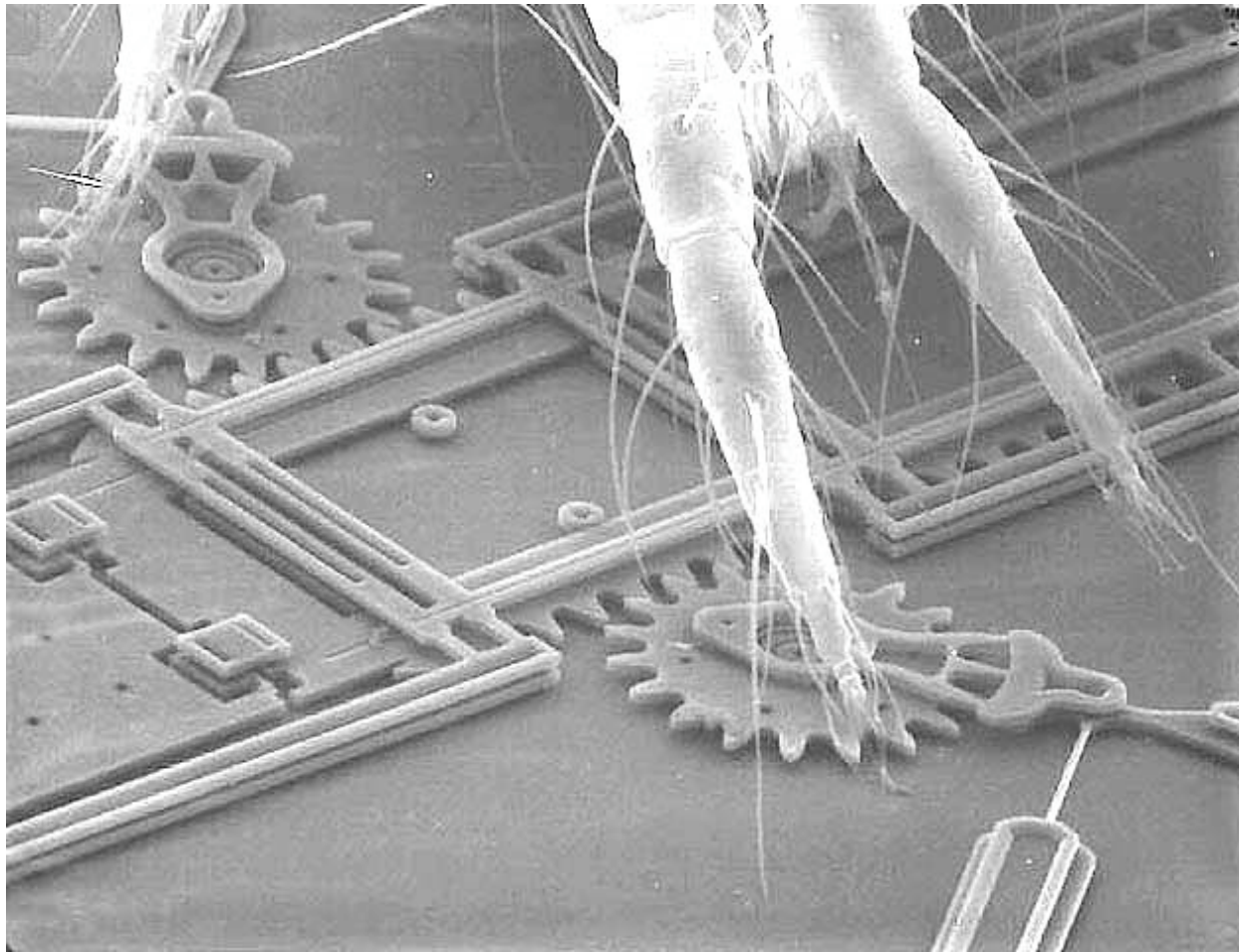
Actuation mechanisms

- MEMS structures can be actuated (= “moved”) **laterally** or **vertically**
- Actuation mechanisms (more in future lectures)
 - **Electrostatic**
 - Capacitor-structures: +/- charges attracted
 - Simple, low energy levels, enough for RF applications
 - **Thermal**
 - **Magnetic**
 - **Piezoelectric**
 - Strain (= “tøyning”) produces an electric field, - and opposite!

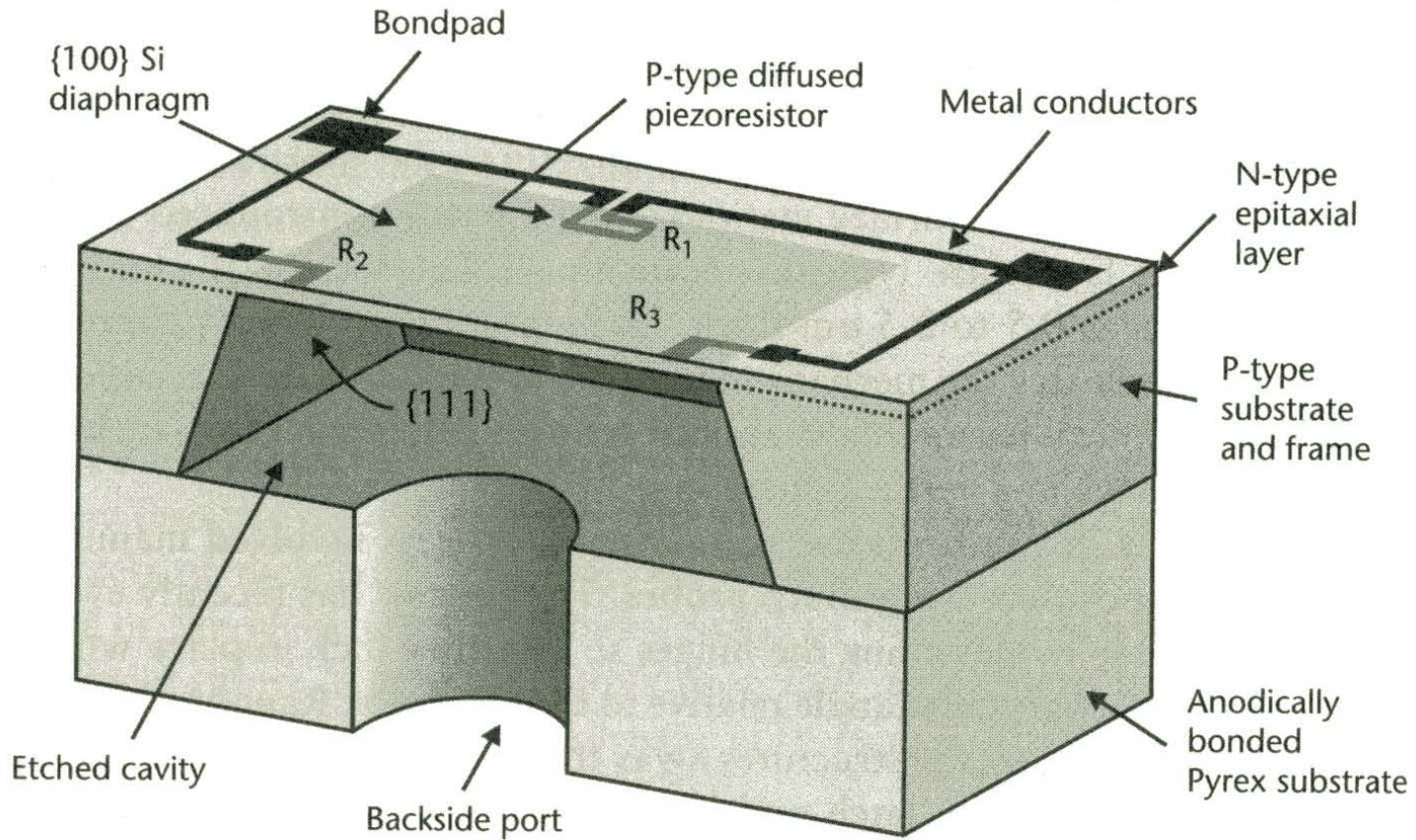
Some applications of MEMS

- **Automotive industry**
 - Micro accelerometers
 - Airbag-sensors (InfineonSensoNor)
 - Tire pressure sensors
- **Oil industry**
 - Pressure sensor in oil wells and oil tubes
- **Navigation**
 - Gyroscope
- **Biomedical**
 - Micro fluidic, chemical analysis
 - Implants
- **Optics**
 - Micro mirrors for projector, micro lenses for mobile phones
- **Computer industry**
 - Ink printer-head
- **Wireless communication**
 - RF MEMS switches

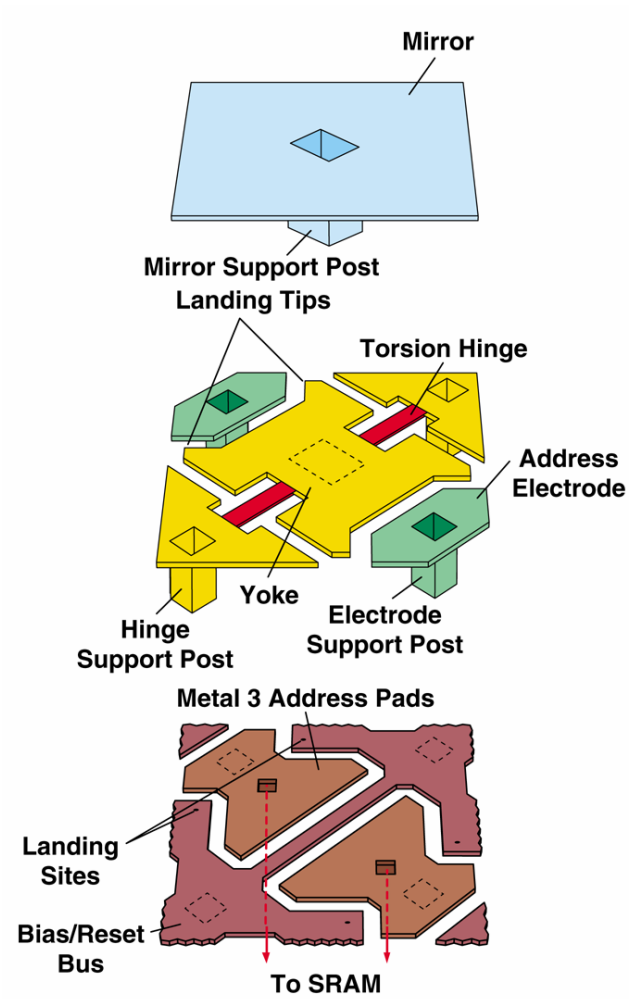
Micro motor fra Sandia



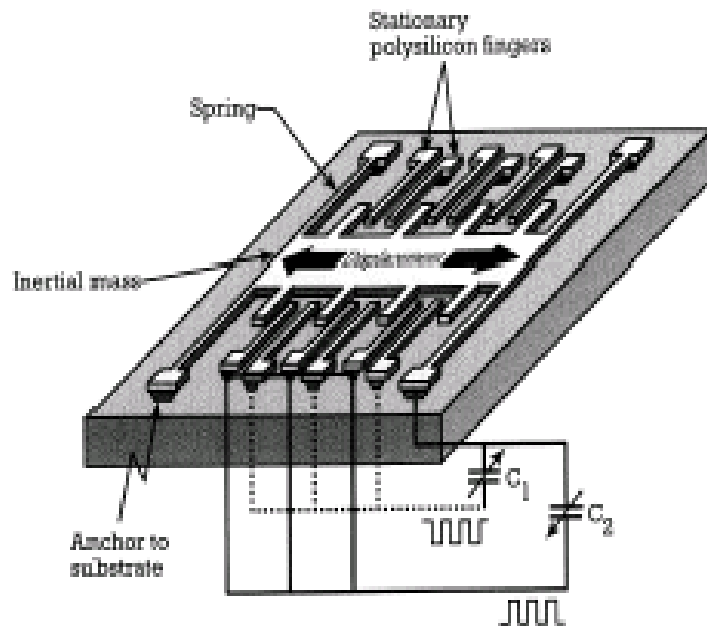
Pressure sensor



Micro mirror

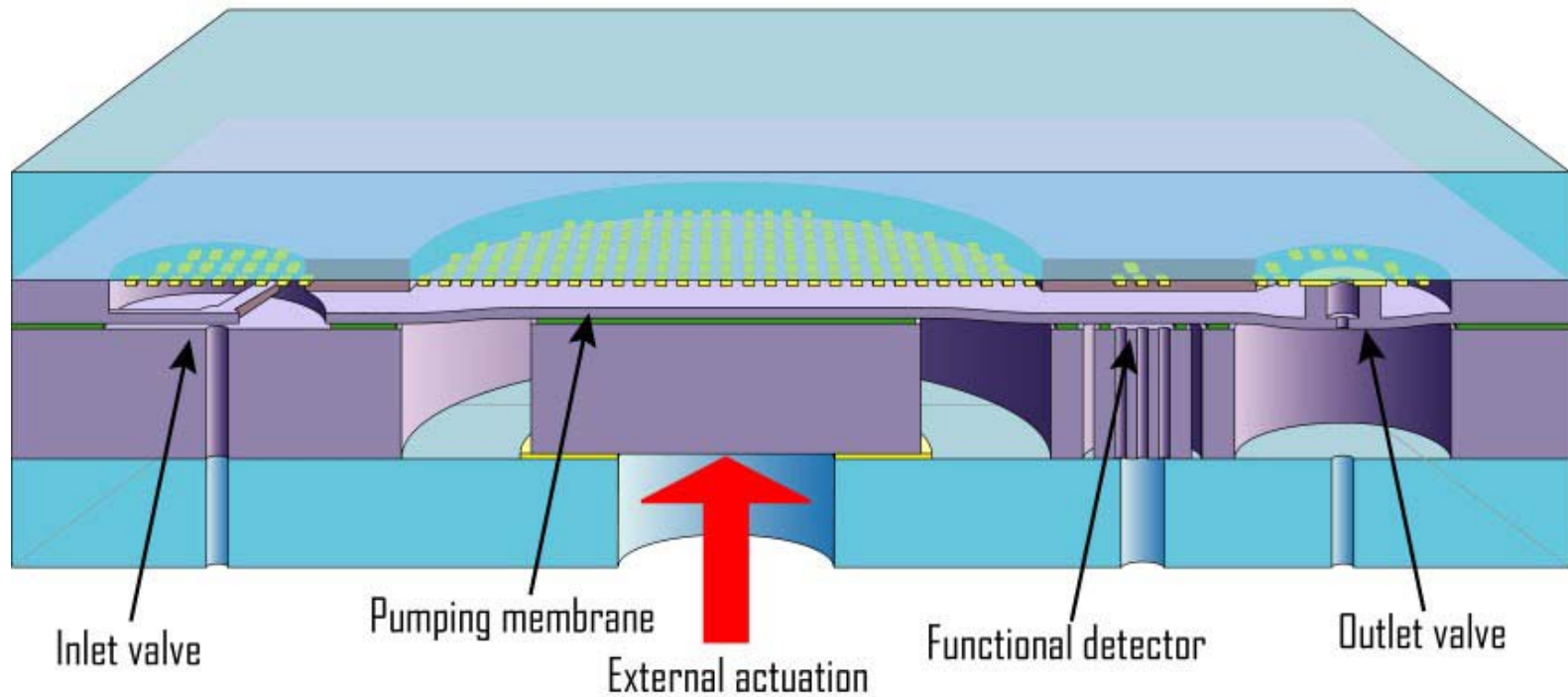


A Capacitive Accelerometer



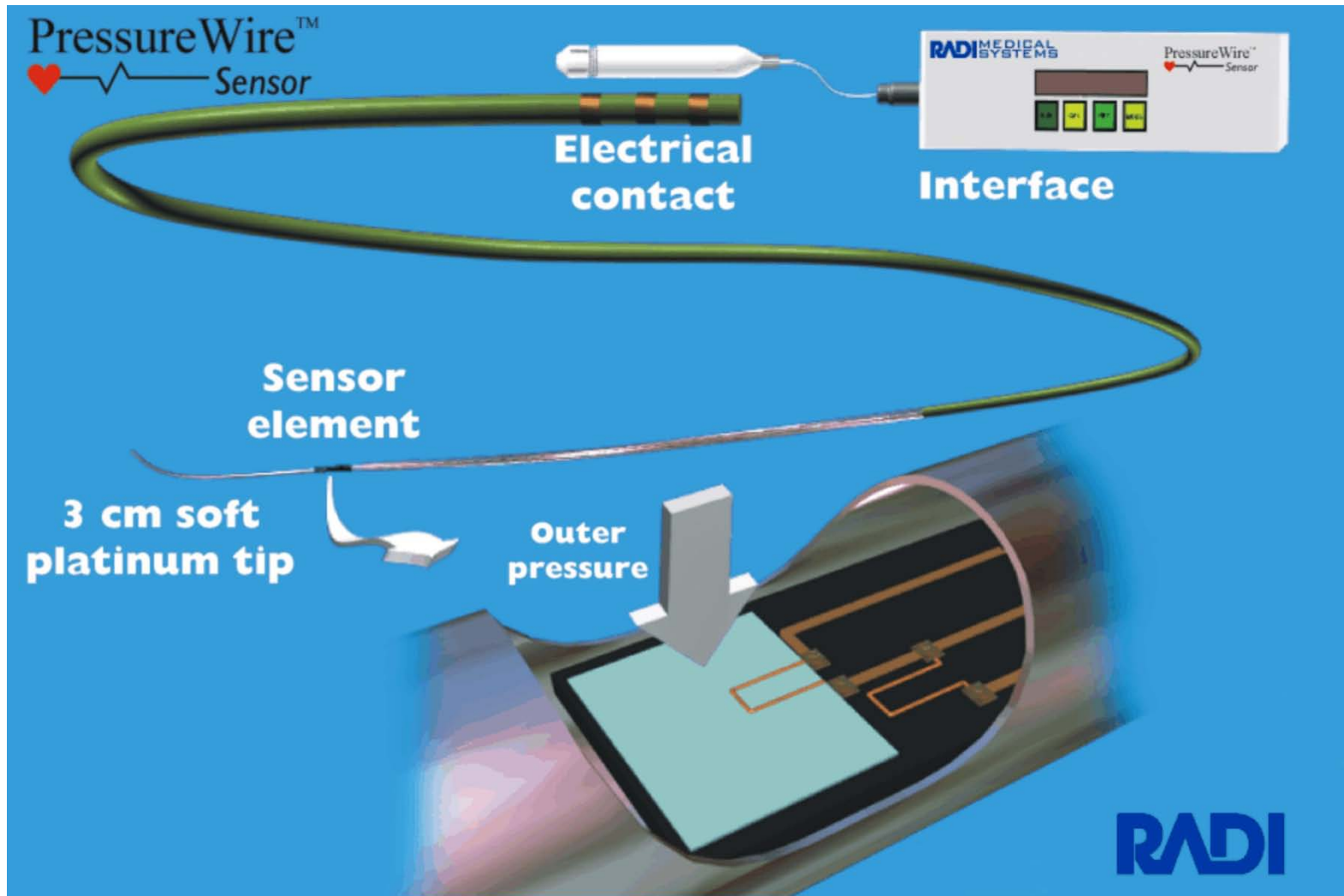
Technology Analysis: Drug Delivery

Debiotech Chip



Source: Debiotech

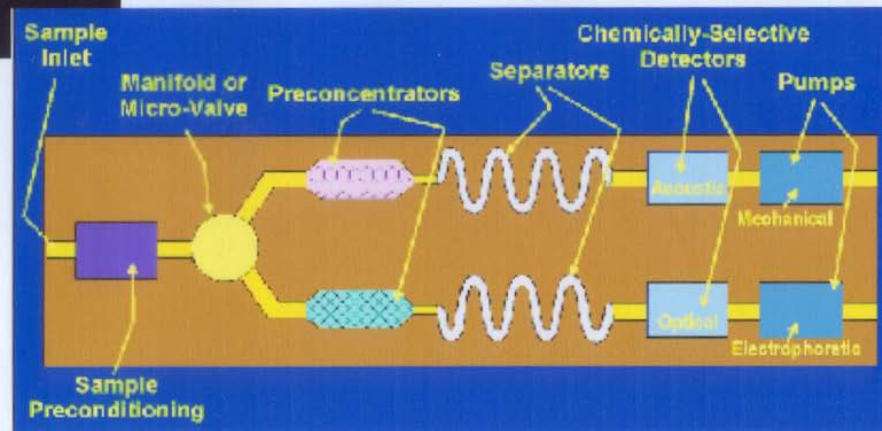
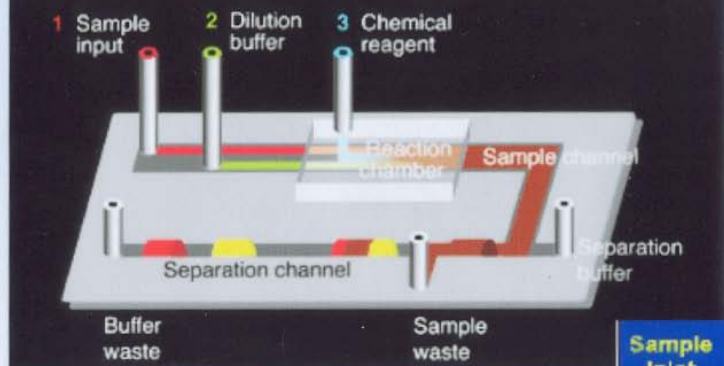
Radi Catheter



Biotechnology MEMS

“Lab-on-a-Chip”

Lab-on-a-chip concept for capillary electrophoresis



iSTAT



- blood analysis
glucose, urea, pH, blood gases,
- portable POC device
- analyser + disposable cartridges
- microfluidic channels
- micro-fabricated thin-film electrodes

Today's lecture

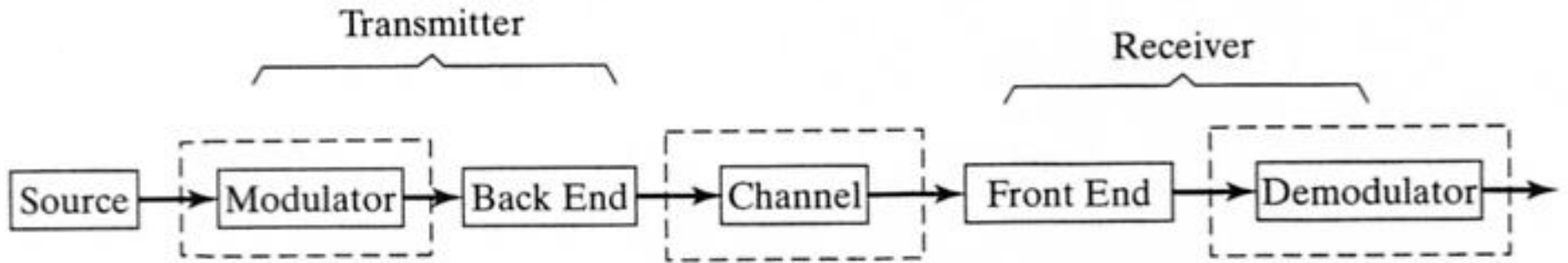
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RF-systems in general

- Radio waves are used for transmitting/receiving
 - Electromagnetic waves (Maxwells equations)
- Basic component: radio **"transceiver"**
 - Transmitter + Receiver
 - Methods for transmission
 - TDMA (Time Division Multiplexing Access)
 - FDMA (Frequency D M A)
- Signal quality depends on
 - Position
 - Environment, reflection
 - "Multipath"
 - Noise (S/N-ratio, BER= bit error rate)

General communication system



Carrier modulation to represent Bit flow

Radio channel introduces noise and interference

Receiver converts the signal before demodulation

→ **High performance components are required!**

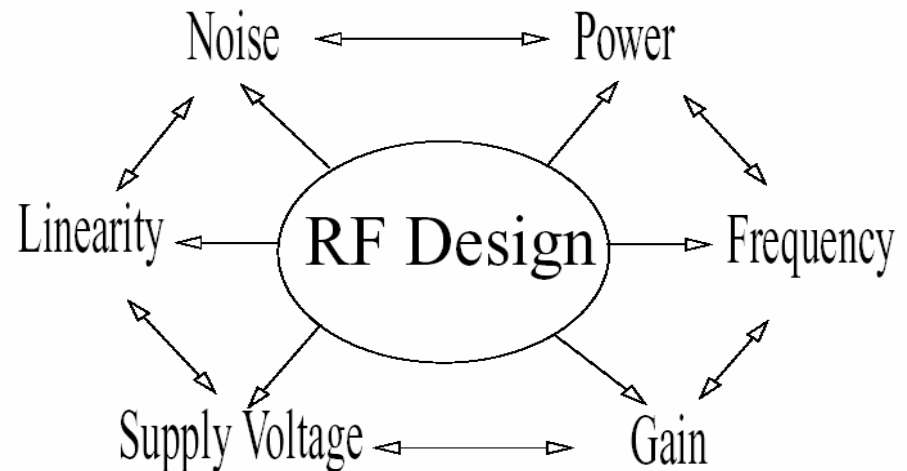
RF-systems

- Efficiency/performance of RF-systems
 - Ability to transfer **power**
 - Simultaneously use of limited **bandwidth**
- The frequency resource is limited
 - "Sharp" RF-filtering needed to separate channels
 - The quality and performance of the RF components are critical to implement wireless communication systems
 - **→ RF MEMS can meet critical requirements!**

RF design

- → **A major challenge for circuit designers!**
 - Many aspects have to be considered when doing RF design

RF Design Hexagon
Multi-objective approach



Jerzy Dabrowski, CMOS RF Transceiver Design, 2004

- CMOS-technology is a strong candidate for implementing critical parts of a transceiver!
 - **BUT not able to fulfill all requirements of component performance**

Implications of RF vs. circuit technology

- Increased frequency:

- → shorter wavelength

- in vacuum:

$$\lambda \cdot f = c$$

- → signal variations in short physical distances

- voltage V , current I are not constant over the component dimension: → waves!

- → smaller component dimensions are desired

- small tolerance fabrication

- → micromachining

Table 1-1 IEEE Frequency Spectrum

Frequency Band	Frequency	Wavelength
ELF (Extreme Low Frequency)	30–300 Hz	10,000–1000 km
VF (Voice Frequency)	300–3000 Hz	1000–100 km
VLF (Very Low Frequency)	3–30 kHz	100–10 km
LF (Low Frequency)	30–300 kHz	10–1 km
MF (Medium Frequency)	300–3000 kHz	1–0.1 km
HF (High Frequency)	3–30 MHz	100–10 m
VHF (Very High Frequency)	30–300 MHz	10–1 m
UHF (Ultrahigh Frequency)	300–3000 MHz	100–10 cm
SHF (Superhigh Frequency)	3–30 GHz	10–1 cm
EHF (Extreme High Frequency)	30–300 GHz	1–0.1 cm
Decimillimeter	300–3000 GHz	1–0.1 mm
P Band	0.23–1 GHz	130–30 cm
L Band	1–2 GHz	30–15 cm
S Band	2–4 GHz	15–7.5 cm
C Band	4–8 GHz	7.5–3.75 cm
X Band	8–12.5 GHz	3.75–2.4 cm
Ku Band	12.5–18 GHz	2.4–1.67 cm
K Band	18–26.5 GHz	1.67–1.13 cm
Ka Band	26.5–40 GHz	1.13–0.75 cm
Millimeter wave	40–300 GHz	7.5–1 mm
Submillimeter wave	300–3000 GHz	1–0.1 mm

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Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters

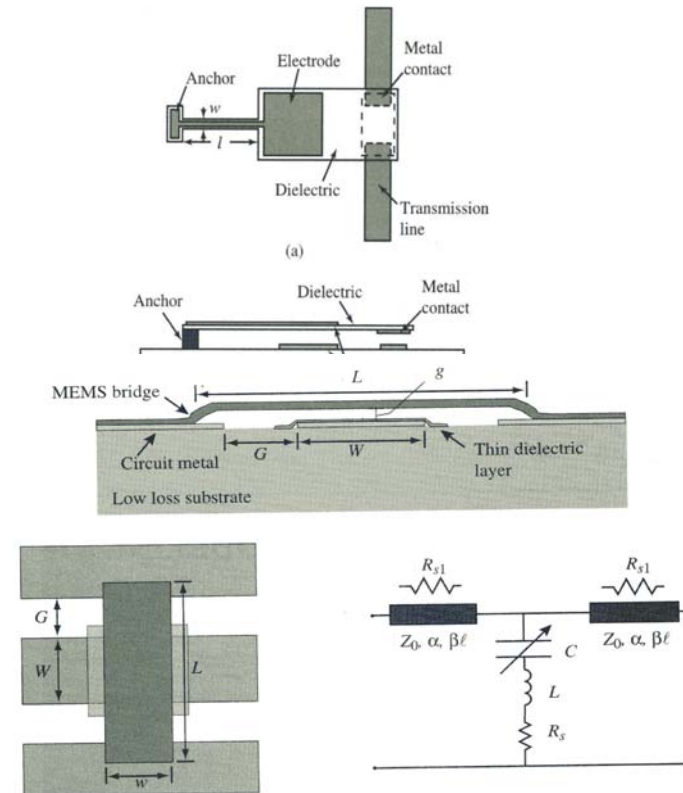
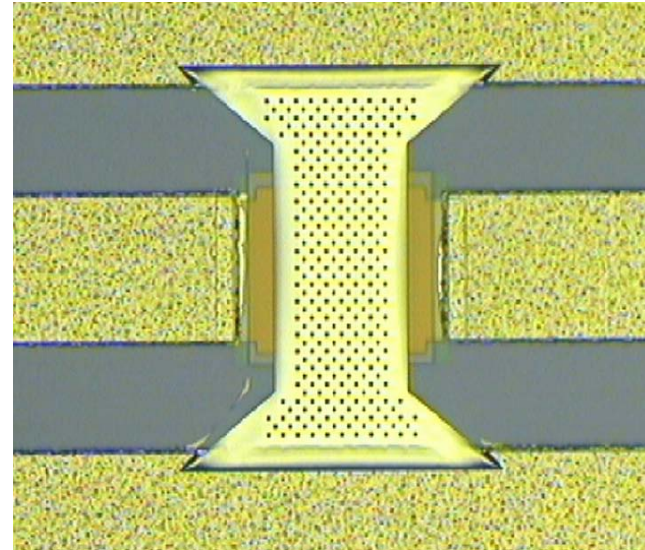


Figure 4.1. Illustration of a typical MEMS shunt switch shown in cross section and plan view. The equivalent circuit is also shown [6] (Copyright IEEE).

Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters

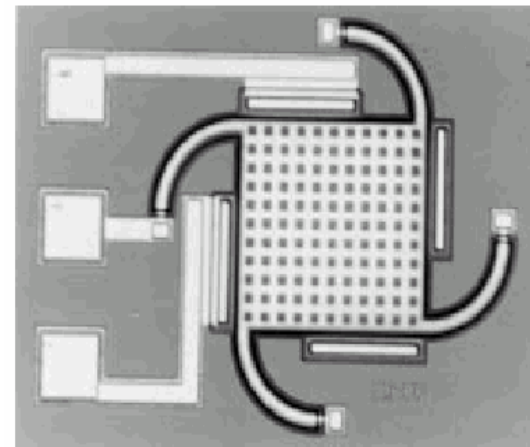
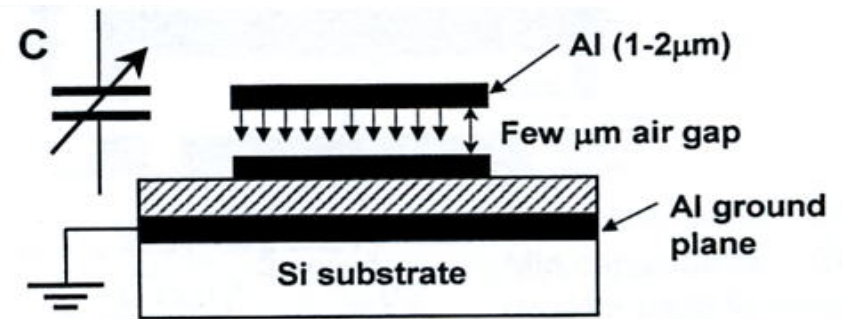


Ex.: microwave switch

- An early application of RF MEMS
 - Much activity, many examples exist
 - Benefits
 - **Electrostatic** actuation is typical: simple principle
 - El voltage → charge → attractive forces → mechanical movement
 - High signal linearity for signals passing the switch
 - Low DC "standby power"
 - Low loss ("insertion loss")
 - Challenges
 - Low switching speed (some μs)
 - Reliability of metal contacts (stiction, micro welding, wear-out)

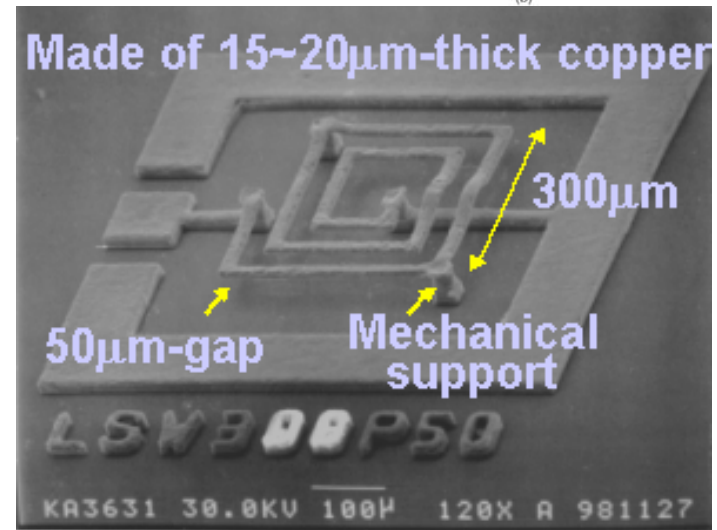
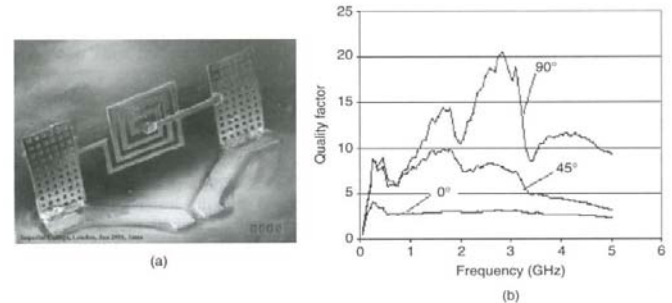
Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters



Typical RF MEMS components

- Switches
- Variable capacitors
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Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters
- MEMS also for:
transmission lines and
antennas

Typical RF MEMS components

- Switches
- Variable capacitors
- Inductors
- Resonators
- Micromechanical filters
- Phase shifters
- **In INF5490: focus on real vibrating structures**
 - - Can be used to implement
 - **oscillators**
 - **filters**
 - **mixers**

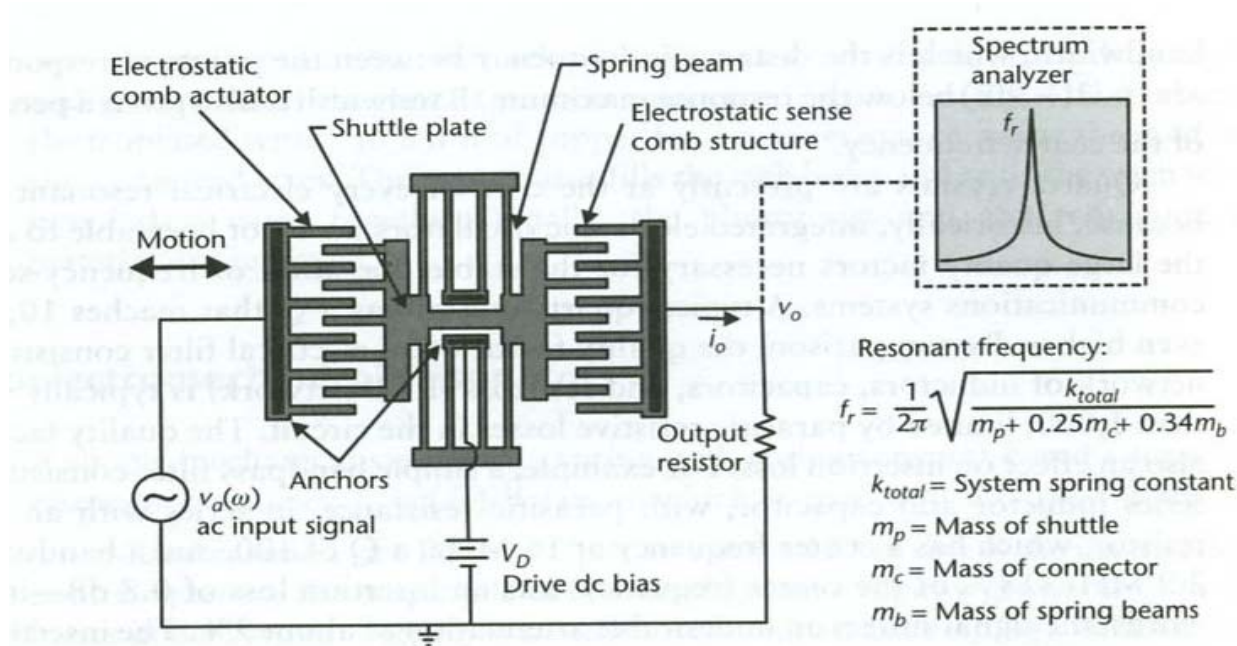
Micro-Electro-Mechanical resonators

High-Q with MEMS resonators: why?

- IC's cannot achieve Q's in the 1000's
 - transistors consume too much power to get Q
 - on-chip spiral inductors: $Q \sim$ low 10's
 - off-chip inductors: Q's in the range of 100's
- **Vibrating mechanical resonances $Q > 1000!$**
- Competitor: quartz crystal resonators (in wristwatches) have extremely high Q's $\sim 10^4 - 10^6$

Source: Clark Nguyen, ESSDERC 2007.

Comb-resonator



lateral (horizontal) movement

Clamped-clamped beam resonator

First-order
resonant frequency:

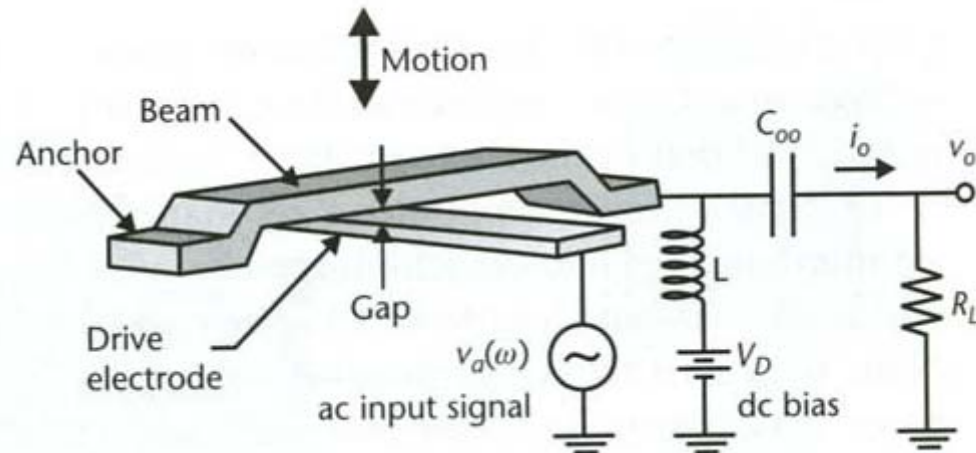
$$f_r = 1.03 \sqrt{\frac{E}{\rho}} \frac{t}{L^2}$$

E = Young's modulus

ρ = Density

t = Beam thickness

L = Beam length



Vertical movement

Challenges in RF transceiver implementation of today

- Performance
- Miniaturization
- Reconfigurability

Challenges in RF transceiver implementation of today

- **Performance**

- *Integrated microelectronic components* have **limited** RF performance
 - Technology: GaAs, bipolar Si, CMOS, PIN-diodes
 - ex. PIN-diode switch (inefficient), RF filter (difficult!)
- **Off-chip components in RF systems** are needed!
 - matching networks, filters
 - crystal oscillators, inductors, variable capacitors

- **Miniaturization**

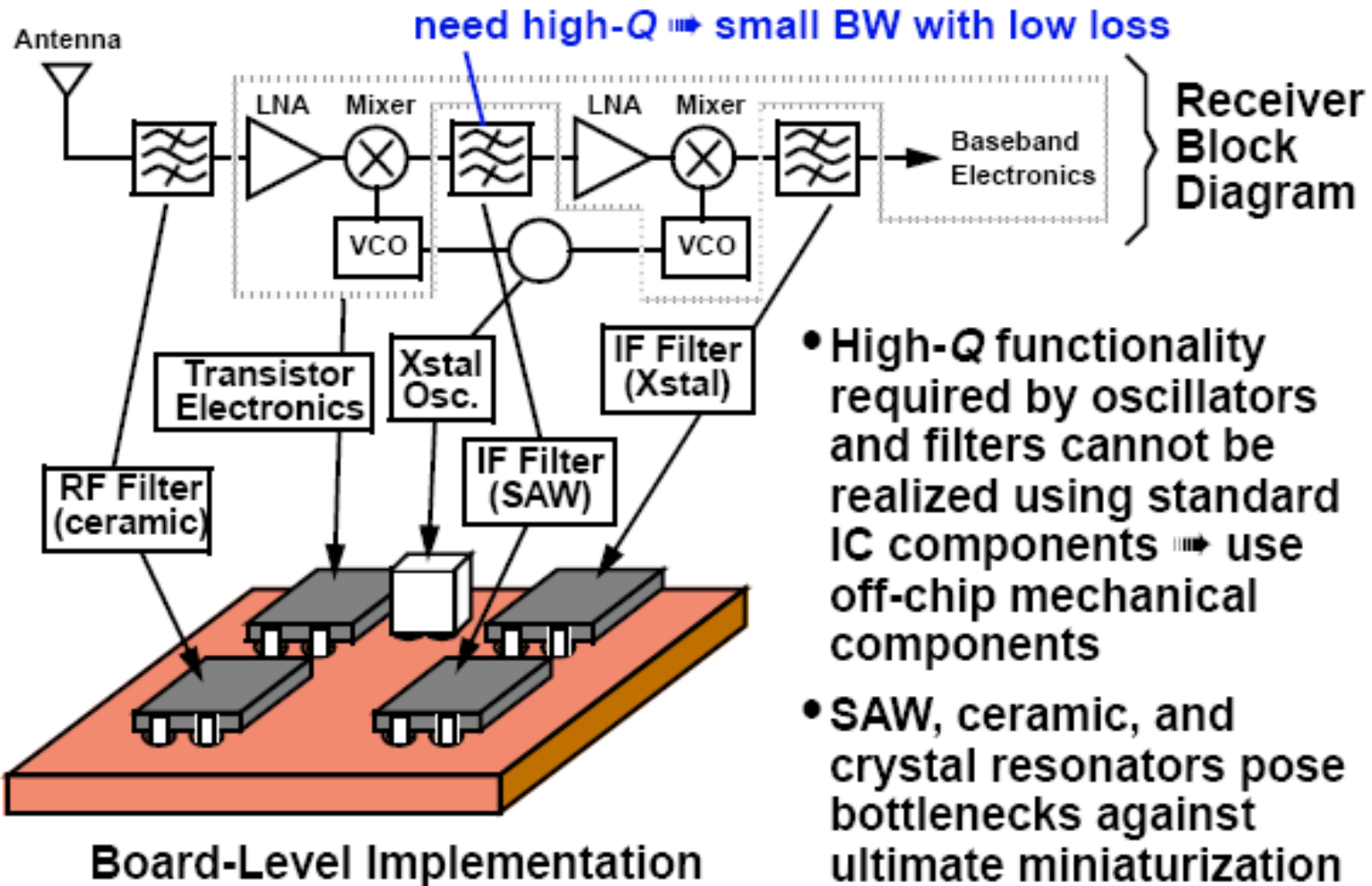
- **Discrete, off-chip** components hinder miniaturization
- PCB → uses up a large space

Challenges in RF transceiver implementation of today

- **Reconfigurability**

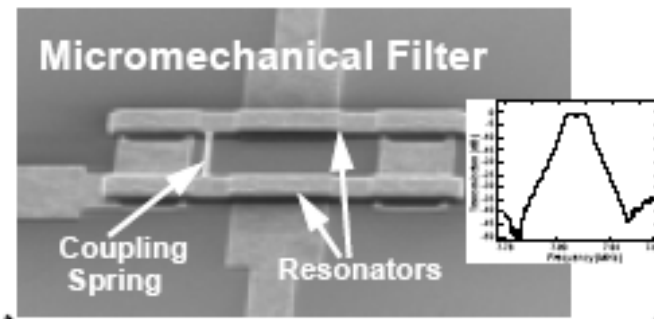
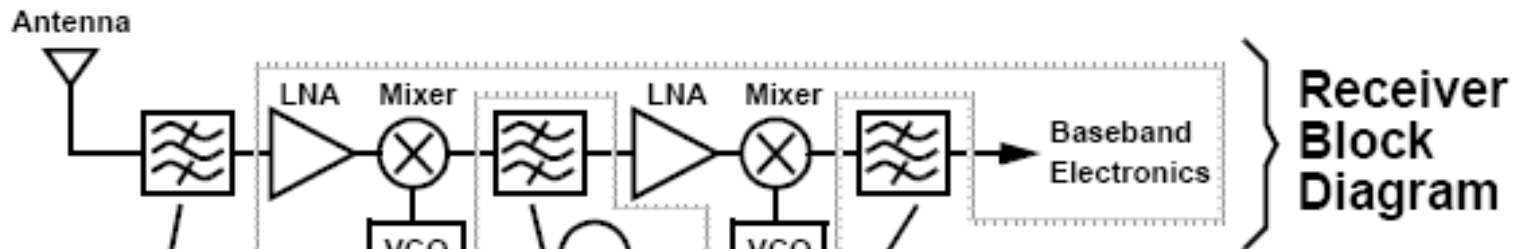
- Increasing demands exist that one single RF transceiver shall cover various standards and channels
 - Programmability is desired
- **Reconfigurable "front-end"** for "sw defined radio"
 - RF MEMS may solve the problem!

Miniaturization of Transceivers



- High-Q functionality required by oscillators and filters cannot be realized using standard IC components \Rightarrow use off-chip mechanical components
- SAW, ceramic, and crystal resonators pose bottlenecks against ultimate miniaturization

Target Application: Integrated Transceivers



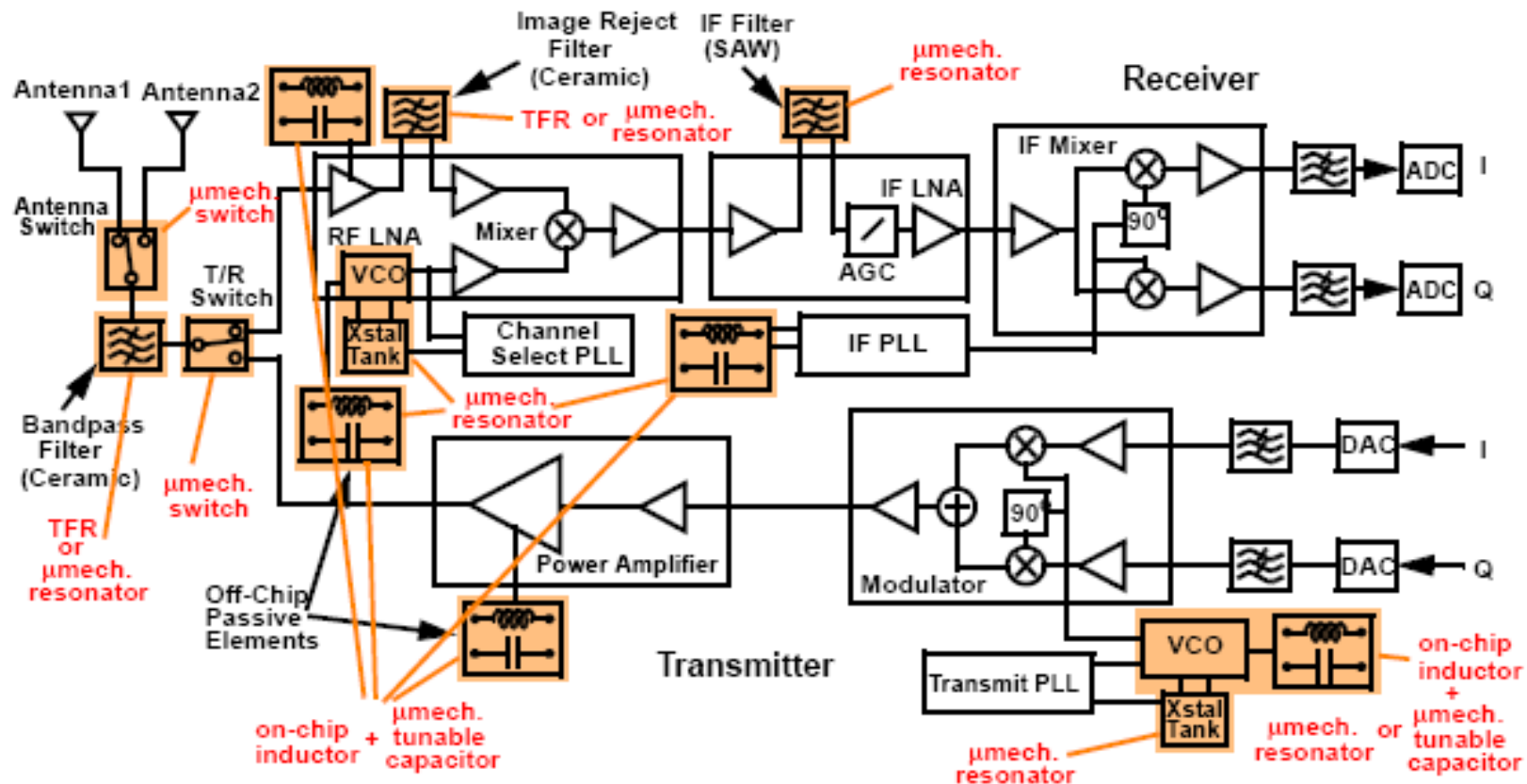
MEMS

↓

Single-Chip Version

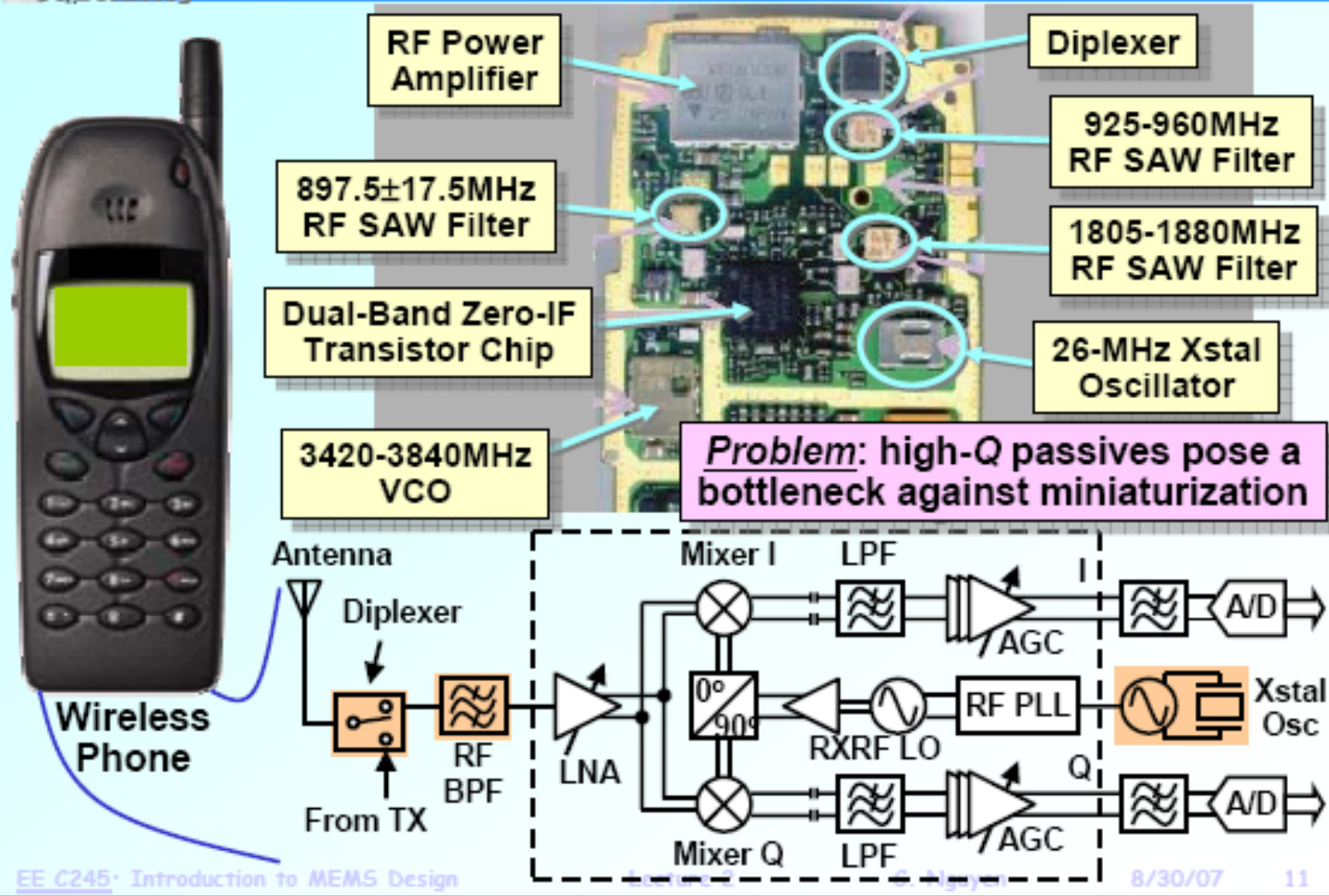
- Off-chip high-Q mechanical components present bottlenecks to miniaturization → replace them with μ mechanical versions

MEMS-Replaceable Transceiver Components



- A large number of off-chip high-Q components replaceable with μmachined versions; e.g., using μmachined resonators, switches, capacitors, and inductors

Miniaturization of RF Front Ends



Benefits of RF MEMS

- Performance
- Power consumption
- Cost
- Miniaturization

Benefits of RF MEMS

- Higher **performance**
 - Increased selectivity: sharp filters
 - Increased Q-factor: **stable** "tank" frequency
 - Reduced loss
 - Higher isolation, reduced cross talk
 - Reduced signal distortion
 - Larger bandwidth
- Lower **power consumption**
- **Reduced cost**
 - Batch processing
- Circuit and system **miniaturization**
 - System integration (μ electronics + MEMS)
 - Packaging: Multi-chip module
 - Monolithic integration: SoC (System-on-Chip)

Use of RF MEMS

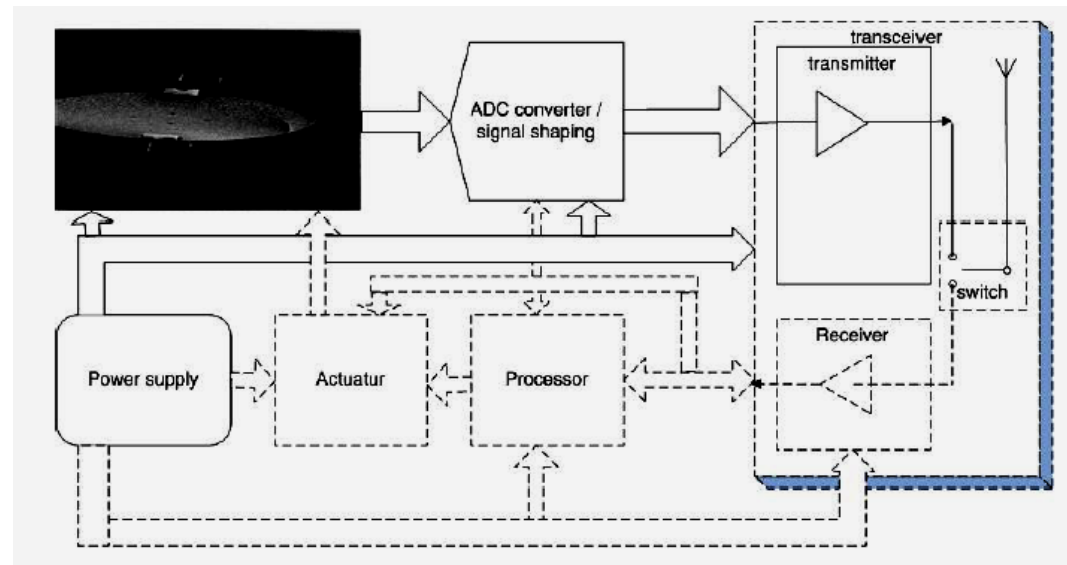
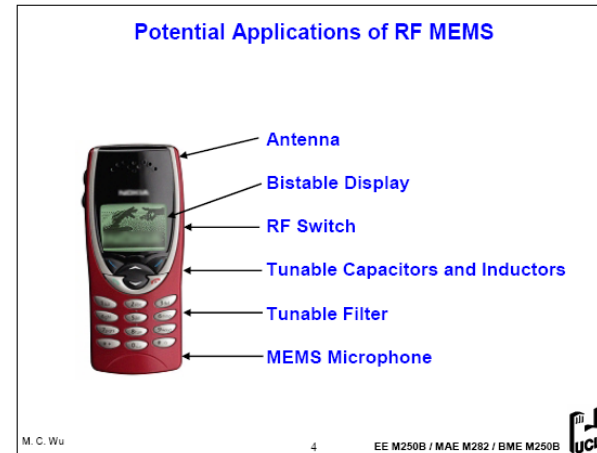
- A) **Replacing** discrete components
- B) **New** integrated functionality
 - New system architectures
 - E.g. implement reconfigurable RF systems by using near ideal RF MEMS switches

New RF architectures

- New ways to design RF systems
 - MEMS technology may be used to implement a lot of small, low cost basic modules
 - Switches may then be used to **switch between the modules**
 - MEMS makes it easier to perform module based design
 - Micromachined **“lumped” (= “discrete”) components** may replace distributed components
 - Enhanced system integration flexibility

Perspectives

- Use of wireless (personal) communication increases
 - 3-4-5 G systems
 - Mobile terminals
 - **Multi-standard** units
 - "15 radio systems in each unit?"
- Wireless sensor networks (WSNs)
 - **Sensors everywhere**
 - compact, intelligent
 - "ambient intelligence"



[J. Ekre]

Current challenges for RF MEMS

- Switch actuation **speed** needs to be increased
 - Typical 1-100 μ s
- Operating **RF frequency** needs to be increased for mechanical resonators and filters
 - Up to some GHz today (3 – 5 GHz)
- Good RF **filter banks** should be implemented
- Higher **reliability** critical
- **Packaging**
 - *Vacuum* often needed
 - Modules of various materials and technologies to be combined
 - SiP – “System-in-Package”
- **Monolithic integration** is desired
 - SoC – System-on-Chip

Integrated solutions?

- Fabrication of microelectronics and MEMS have much in common
- Combination of electronics and micromechanics?
 - Integrated solutions on a Si chip
 - → **”Radio-on-a-chip”!**
 - One option: CMOS-MEMS (another lecture)

MEMS for wireless integration

Intel Developer Forum Spring 2002

MEMS for wireless integration

Today

BASE BAND PROCESSOR RF CHIP

100s of passive components

Future (3 - 4 Yrs)

RF MEMS CHIP

BASE BAND RF

RF MEMS CHIP

Future (4+ Yrs)

BASE BANDS RF & MEMS CHIP

- Silicon integration follows Moore's law
- MEMS research to enable:
 - "High Value" passives (Filters, Switches etc) to be built from Silicon and integrated together

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